

Description

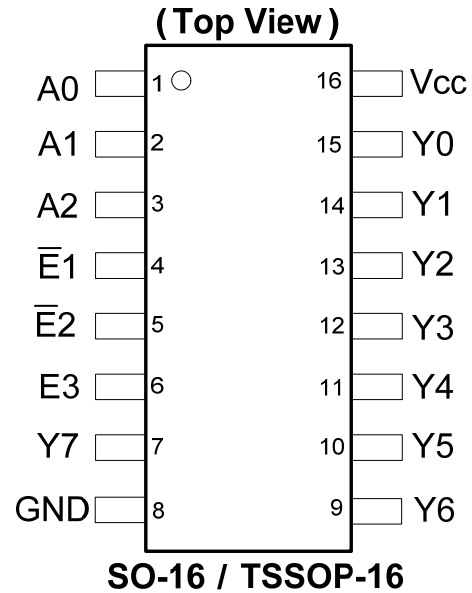
The 74HCT138 is a high speed CMOS device that is designed to be pin compatible with 74LS low power Schottky types.

The device accepts a three bit binary weighted address on input pins A0, A1 and A2 and when enabled will produce one active low output with the remaining seven being high.

There are two active LOW enable inputs $\bar{E}1$ and $\bar{E}2$, and one active HIGH enable input E3. The disabled device state results in all outputs being high. The enable state occurs with $\bar{E}1$ and $\bar{E}2$ asserted low and E3 asserted high.

The multiple enable lines allow for the parallel expansion of decoders to create 4-to-16 line versions with no additional parts and 5-to-32 versions with the addition of a single inverter.

Pin Assignments



Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Sinks or sources 8mA at $V_{CC} = 4.5V$
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs accept up to 6.0V
- ESD Protection Tested per JESD 22
- Exceeds 200-V Machine Model (A115-A)
- Exceeds 2000-V Human Body Model (A114-A)
- Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Applications

- Memory chip select decoding
- Demultiplexing
- Single line peripheral control
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed.

[Click here for ordering information, located at the end of datasheet](#)

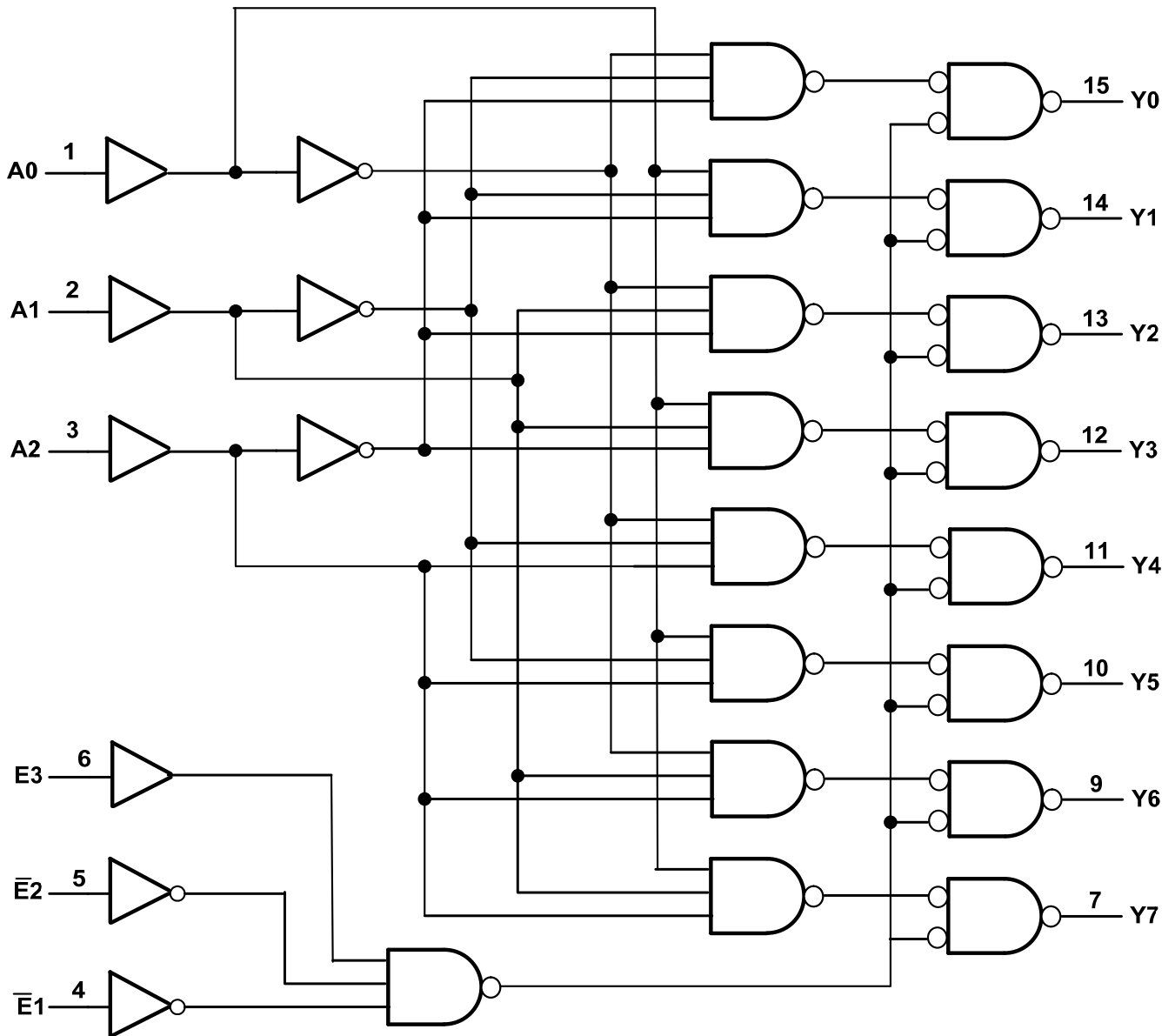
Pin Descriptions

Pin Number	Pin Name	Description
1	A0	Address Input 0
2	A1	Address Input 1
3	A2	Address Input 2
4	$\bar{E}1$	Enable Input 1 (active LOW)
5	$\bar{E}2$	Enable Input 2 (active LOW)
6	E3	Enable Input 3 (active HIGH)
7	Y7	Output 7 (active LOW)
8	GND	Ground
9	Y6	Output 6 (active LOW)
10	Y5	Output 5 (active LOW)
11	Y4	Output 4 (active LOW)
12	Y3	Output 3 (active LOW)
13	Y2	Output 2 (active LOW)
14	Y1	Output 1 (active LOW)
15	Y0	Output 0 (active LOW)
16	V _{cc}	Supply Voltage

Function Table Diagram

Control			Input			Output							
$\bar{E}1$	$\bar{E}2$	E3	A2	A1	A0	$\bar{Y}7$	$\bar{Y}6$	$\bar{Y}5$	$\bar{Y}4$	$\bar{Y}3$	$\bar{Y}2$	$\bar{Y}1$	$\bar{Y}0$
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X	–	–	–	–	–	–	–	–	–	–	–
X	X	L	–	–	–	–	–	–	–	–	–	–	–
L	L	H	–	–	–	–	–	–	–	–	–	–	–
–	–	–	L	L	L	H	H	H	H	H	H	H	L
–	–	–	L	L	H	H	H	H	H	H	H	L	H
–	–	–	L	H	L	H	H	H	H	H	L	H	H
–	–	–	L	H	H	H	H	H	H	L	H	H	H
–	–	–	H	L	L	H	H	H	L	H	H	H	H
–	–	–	H	L	H	H	H	L	H	H	H	H	H
–	–	–	H	H	L	H	L	H	H	H	H	H	H
–	–	–	H	H	H	L	H	H	H	H	H	H	H

Logic Diagram



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 7.0	V
V _I	Input Voltage Range	-0.5 to 7.0	V
V _O	Voltage Applied to Output in High or Low State	-0.3 to V _{CC}	V
I _{IK}	Input Clamp Current V _I < -0.5V	-20	mA
I _{IK}	Input Clamp Current V _I > V _{CC} + 0.5V	20	mA
I _{OK}	Output Clamp Current V _O < -0.5V	-20	mA
I _{OK}	Output Clamp Current V _O > V _{CC} + 0.5V	20	mA
I _O	Continuous Output Current	+/- 25	mA
I _{CC}	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
T _J	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage	–	4.5	5.5	V
V _I	Input Voltage	–	0	V _{CC}	V
V _O	Output Voltage	Active Mode	0	V _{CC}	V
Δt/ΔV	Input transition rise or fall rate	V _{CC} = 4.5V	–	100	ns/V
T _A	Operating free-air temperature	–	-40	125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V _{CC}	T _A = 25°C			-40°C to 85°C		-40°C to 125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V _{IH}	High-level Input Voltage	—	4.5V to 5.5V	2.0	1.6	—	2.0	—	2.0	—	V
V _{IL}	Low-level input voltage	—	4.5V to 5.5V	—	1.2	0.8	—	0.8	—	0.8	V
V _{OH}	High Level Output Voltage	I _{OH} = -20 µA	4.5V	4.4	4.5	—	4.4	—	4.4	—	V
		I _{OH} = -4 mA	4.5V	3.98	4.32	—	3.85	—	3.7	—	
V _{OL}	Low-level Output Voltage	I _{OL} = 20 µA	4.5V	—	0	0.1	—	0.1	—	0.1	V
		I _{OL} = 4 mA	4.5V	—	0.15	0.26	—	0.33	—	0.4	
I _I	Input Current	V _I = GND to 5.5 V	5.5V	—	—	±0.1	—	± 1	—	± 1	µA
I _{CC}	Supply Current	V _I = GND or V _{CC} I _O = 0	5.5V	—	—	8.0	—	80	—	160	µA
ΔI _{CC}	Additional Supply Current	Test Per Pin V _I = V _{CC} -2.1 V Other V _I = V _{CC} or GND I _O = 0	4.5V to 5.5V	—	150	540	—	675	—	735	µA
				—	125	450	—	563	—	613	
				—	100	360	—	450	—	490	µA
C _i	Input Capacitance	V _I = V _{CC} or GND	5.5V	—	4	10	—	10	—	10	pF

Switching Characteristics

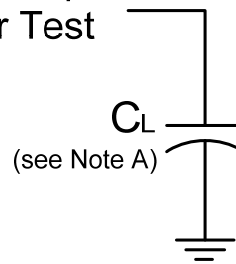
Symbol / Parameter	Pins	Test Conditions	V _{CC}	T _A = 25°C			-40°C to 85°C		-40°C to 125°C		Unit
				Min	Typ.	Max	Min	Max	Min	Max	
t _{PLH} , t _{PLH} Propagation Delay	An to $\bar{Y}_n$	Figure 2	4.5V	—	20	35	—	35	—	45	ns
			5.0V	—	17	—	—	—	—	—	
	E3 to $\bar{Y}_n$	Figure 2	4.5V	—	18	40	—	40	—	45	
			5.0V	—	19	—	—	—	—	—	
	$\bar{E}_n$ to $\bar{Y}_n$	Figure 2	4.5V	—	19	40	—	40	—	45	
			5.0V	—	19	—	—	—	—	—	
t _{TLH} , t _{THL} Transition Time	$\bar{Y}_n$	Figure 2	4.5 V	—	7	15	—	15	—	110	ns

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

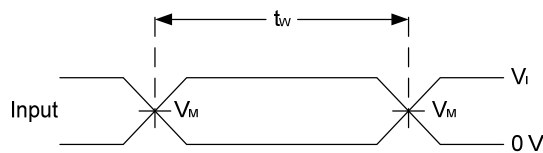
Parameter		Test Conditions	V _{CC} = 5V	Unit
			TYP	
C _{pd}	Power Dissipation Capacitance	f = 1 MHz all outputs switching-no load	21	pF

Parameter Measurement Information

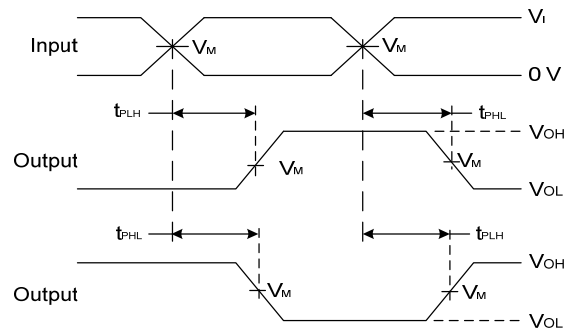
From Output
Under Test



V _{CC}	Inputs		V _M	C _L
	V _I	t _r /t _f		
4.5V	3 V	6ns	V _{CC} /2	50pF
5.0V	3 V	6ns	V _{CC} /2	15pF used for 5V typical test



**Voltage Waveform
Pulse Duration**

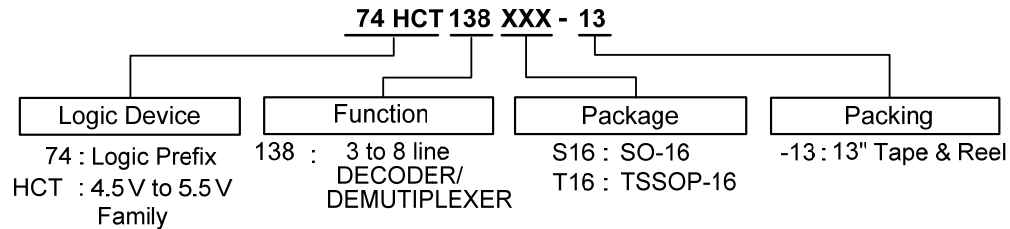


**Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs**

- Notes: A . Includes test lead and test apparatus capacitance.
 B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
 C. Inputs are measured separately one transition per measurement
 D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 1. Load Circuit and Voltage Waveforms

Ordering Information

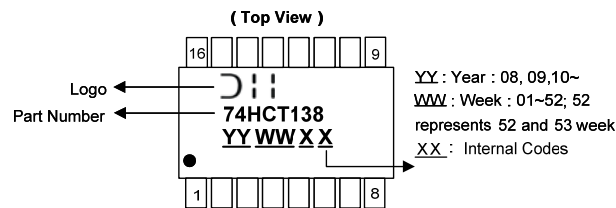


Device	Package Code	Packaging (Note 6)	7" Tape and Reel(Note 7)	
			Quantity	Part Number Suffix
74HCT138S16-13	S16	SO-16	2500/Tape & Reel	-13
74HCT138T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Notes: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
<http://www.diodes.com/datasheets/ap02001.pdf>.
 7. The taping orientation is located on our website at <http://www.diodes.com/datasheets/ap02007.pdf>

Marking Information

(1) SO-16, TSSOP-16

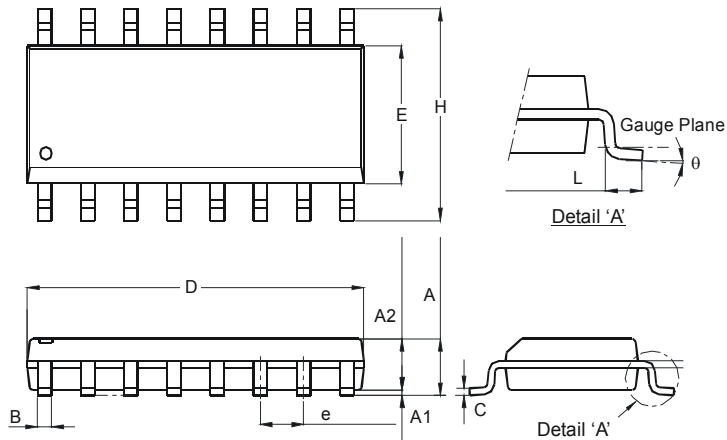


Part Number	Package
74HCT138S16	SO-16
74HCT138T16	TSSOP-16

Package Outline Dimensions (All dimensions in mm.)

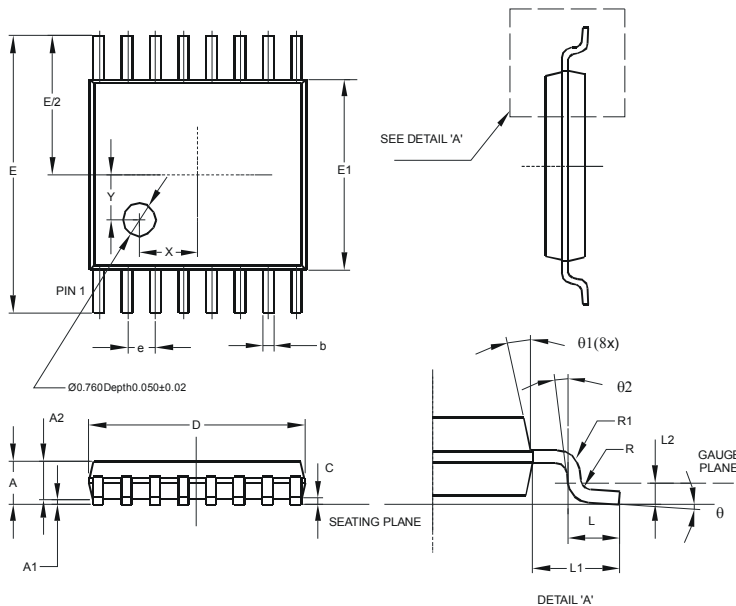
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

Package Type: SO-16



SO-16		
Dim	Min	Max
A	1.40	1.75
A1	0.10	0.25
A2	1.30	1.50
B	0.33	0.51
C	0.19	0.25
D	9.80	10.00
E	3.80	4.00
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-16

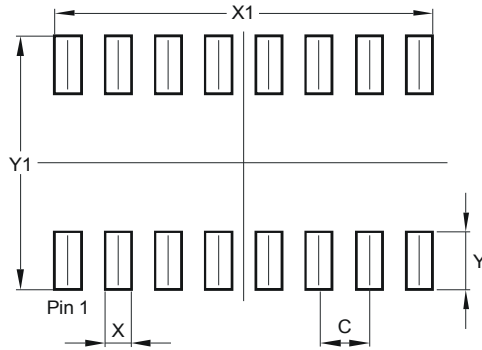


TSSOP-16			
Dim	Min	Max	Typ
A	-	1.08	-
A1	0.05	0.15	-
A2	0.80	0.93	-
b	0.19	0.30	-
c	0.09	0.20	-
D	4.90	5.10	-
E	6.40 BSC		
E1	4.30	4.50	-
e	0.65 BSC		
L	0.45	0.75	-
L1	1.00 REF		
L2	0.25 BSC		
R	0.09	-	-
R1	0.09	-	-
X	-	-	1.350
Y	-	-	1.050
θ	0°	8°	-
θ1	5°	15°	-
θ2	0°	-	-
All Dimensions in mm			

Suggested Pad Layout

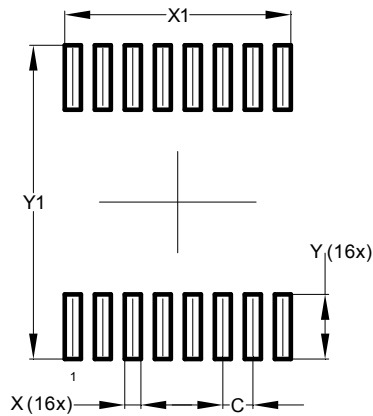
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)
C	1.270
X	0.670
X1	9.560
Y	1.450
Y1	6.400

Package Type: TSSOP-16



Dimensions	Value (in mm)
C	0.650
X	0.350
X1	4.900
Y	1.400
Y1	6.800

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

www.diodes.com

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9